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Quad. 2-input OR Gates



ADE-205-417 (Z) 1st. Edition Sep. 2000

#### **Features**

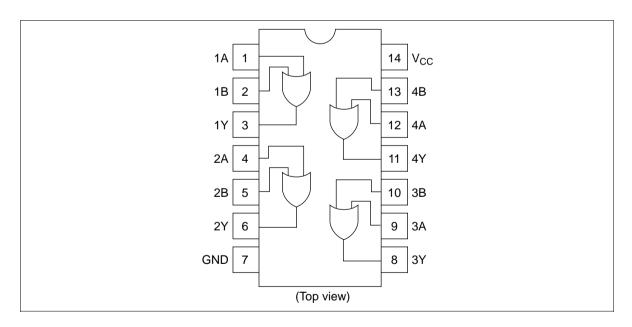
High Speed Operation: t<sub>pd</sub> = 10 ns typ (C<sub>L</sub> = 50 pF)
 High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2$  to 6 V

• Low Input Current: 1 µA max

• Low Quiescent Supply Current:  $I_{CC}$  (static) = 1  $\mu$ A max (Ta = 25°C)

### **Pin Arrangement**



## **DC** Characteristics

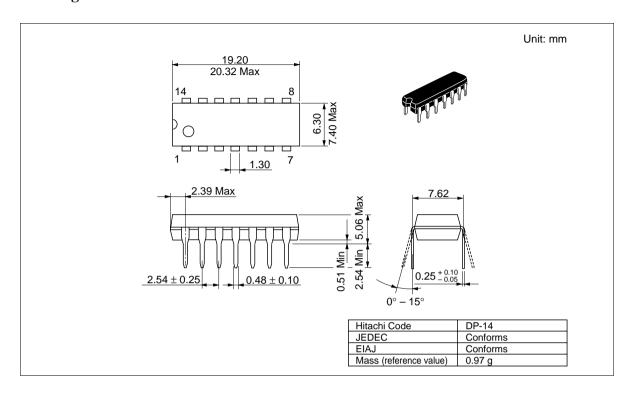
			Ta = 25°C		Ta = −40 to +85°C		_			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Condition	ns
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	i —		3.15	_	_		
		6.0	4.2	_	_	4.2	_	=		
	V <sub>IL</sub>	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35	_		
		6.0	_	_	1.8	_	1.8	=		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	_	1.9	_	V	Vin = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_	=		
		6.0	5.9	6.0	_	5.9	_	=		
		4.5	4.18	s —	_	4.13	_	=		$I_{OH} = -4 \text{ mA}$
		6.0	5.68	3 —	_	5.63	_	=		$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	Vin = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA
		4.5	_	0.0	0.1	_	0.1	=		
		6.0	_	0.0	0.1	_	0.1	=		
		4.5	_	_	0.26	_	0.33	_		I <sub>OL</sub> = 4 mA
		6.0	_	_	0.26	_	0.33	_		I <sub>OL</sub> = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GND	
Quiescent supply current	I <sub>cc</sub>	6.0	_	_	1.0	_	10	μΑ	Vin = V <sub>cc</sub> or Gf	ND, lout = $0 \mu A$

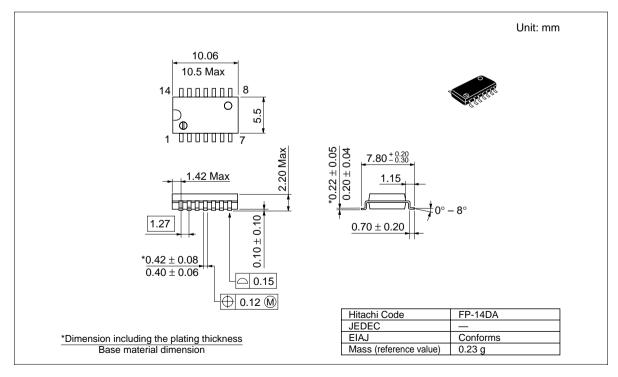
**AC Characteristics** ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

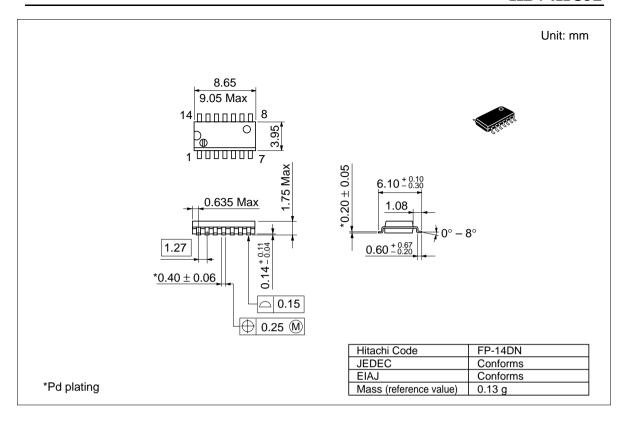
Ta = -40 to Ta = 25°C +85°C

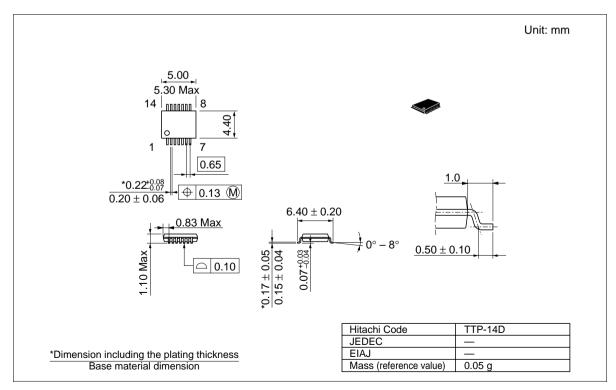
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	_	100	_	125	ns	
time		4.5	_	10	20	_	25		
		6.0	_	_	17	_	21	_	
	t <sub>PHL</sub>	2.0	_	_	100	_	125	ns	
		4.5	_	10	20	_	25		
		6.0	_	_	17	_	21	=	
Output rise time	t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
		4.5	_	5	15	_	19		
		6.0	_	_	13	_	16		
Output fall time	t <sub>THL</sub>	2.0	_	_	75	_	95	ns	
		4.5	_	5	15	_	19		
		6.0	_	_	13	_	16	=	
Input capacitance	Cin	_	_	5	10	_	10	pF	

## **Package Dimensions**









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